

Report No: 138-8

Sample No:

CONFIDENTIAL

### REPORT: Wafer grooving by Laser-MicroJet<sup>®</sup>

for Anonymous

by Jerry Chera; Synova USA

#### **TASK**

The Laser-MicroJet® technology has been tested for cutting groves in multilayer silicon wafer.

#### SAMPLE DESCRIPTION AND PREPARATION

SAMPLE	Material	Polyimide+Al +		
		Oxide+CSC+Si+Backmetal		
	Dimension	Dia = 150 <i>mm</i>		
	Thickness	~500 μm		
	Quantity	2 pcs		
	•			

#### Detailed material description:-

• layer:	1 <sup>st</sup>	Polyimide	thickness:	5 μm
• layer:	2 <sup>end</sup>	Aluminium (minimal in saw street)	thickness:	4 μm (marker)
• layer:	3 <sup>rd</sup>	Oxide	thickness:	5 μm
• layer:	4 <sup>th</sup>	Compound Semiconductor (CSC)	thickness:	5 μm
• layer:	5 <sup>th</sup>	Silicon	thickness:	480 μm
• layer	6 <sup>th</sup>	Backmetal	thickness:	1 μm

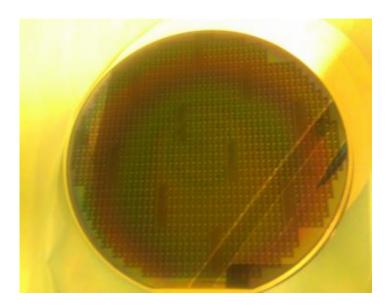
Release of application report					
	Project Leader		Responsible Application Group		
Name:	Jerry Chera	Name:	D <sup>r</sup> Benjamin Carron		
Date:	08.19.2013	Date:	08.21.2013		
Visum:	JC	Visum:	BC		



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#### PROCESS: INSTRUMENT & TEST PARAMETERS

For these experiments, the LDS200 equipped with a frequency-doubled Q-switched Nd:YAG laser has been used as the machine configuration in our lab.

It is a clean-room compatible machine, allowing to cut, drill, groove, scribe, trench, mark, or grind wafers of any kind of material.

Major advantages of Laser-MicroJet® technology with regards to your application are:

- Cutting of arbitrary shapes
- No chipping on front side, minimal chipping on backside
- Negligible heat damage to the material

In the table below, the optimized processing parameters used in the experiments are summarized:



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### First Set of Experment With 70 Micron Nozzle

	SYSTEM	Machine type	LDS200		
Nonz sar					
	MICROJET <sup>®</sup> PARAMETER	Nozzle diameter	70 μm		
		MicroJet <sup>®</sup>	55 μm		
		diameter	·		
		Water pressure	250 <i>bar</i>		
		Assist gas	He		
	LASER PARAMETER	Laser type	LDP-200MQG		
		Wavelength	532 <i>nm</i>		
		Pulse frequency	40 <i>kHz</i>		
		Average power	Internal power = 30 W		
		Other Parmeters	SHG 24.9.9, He 1.00		
			Diode Current = 65%		
	CUTTING PARAMETER	Cutting speed	150 <i>mm/</i> s		
		Number of passes	2		
		Process time	7 mins for verve wafer.		
		Misc Info	No info available for		
			Elvis wafer as it was cut		
			with 50 micron nozzle.		



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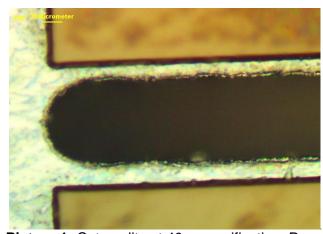
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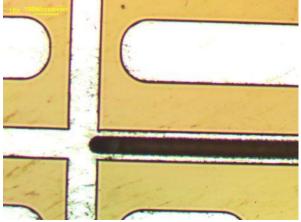
#### **RESULTS**

#### Edge Quality

The following microscope pictures give an overview on the quality obtained with the Laser-Microjet® technology.



**Picture 1:** Cut quality at 40x magnification. Pre clean.



**Picture 2:** Cut quality at 10x magnification. Pre clean.

#### **CONCLUSION**

The grooving of multilayer silicon wafer was investigated on SYNOVA LDS200. This machine is based on the MicroJet® technology and combines the advantages of the high energy pulsed laser with a hair-thin water jet. While the laser is used for material ablation, the water jet is used for guiding the laser light, cooling the edges and preventing the sample from particle contamination, advantages that are essential for cutting of such kind of materials with high quality.

- The results showed a very good quality cut as shown in the pics.
- Very small HAZ ( Heat Affected Zone ).
- Good edge quality.

We thank you for your interest in our technology and our sales manager will contact you soon to obtain a feedback about the analysis of these results and to discuss with you the further steps.

SECOND SET OF EXPERIMENTS WITH THE 50 MICRON NOZZLE to be followed in the next page



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#### **Second Set of Experment With 50 Micron Nozzle**

	SYSTEM	Machine type	LDS200	
Nonz StT				
	MICROJET <sup>®</sup>	Nozzle diameter	50 μm	_
	PARAMETER	MicroJet <sup>®</sup> diameter	45 μm	
		Water pressure	250 <i>bar</i>	
		Assist gas	He	
	LASER PARAMETER	Laser type	LDP-200MQG	
		Wavelength	532 <i>nm</i>	
		Pulse frequency	40 <i>kHz</i>	
		Average power	Internal power = 19 W Pwr in waterjet = 9 W	
		Other Parmeters	SHG 24.9.9, He 1.00 Diode Current = 58% Pulse Width = 700 ns	
	CUTTING PARAMETER	Cutting speed Number of passes	150 <i>mm/</i> .	s_
		Process time	11 mins for Verve wafer & 5 mins for Elvis wafer	_
		Misc Info	There are two sets of wafers with different pitch. One is called Verve and other called Elvis.	



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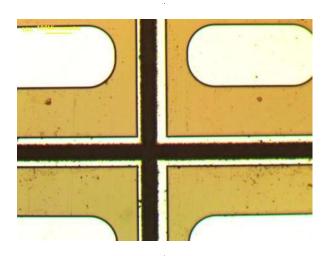
Sample No:

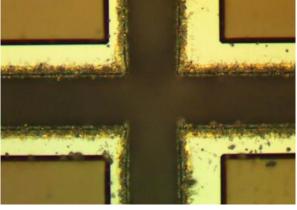
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#### **RESULTS**

#### Edge Quality

The following microscope pictures give an overview on the quality obtained with the Laser-Microjet® technology.





**Picture 3:** Cut quality at 10x magnification. Pre clean.

**Picture 4:** Cut quality at 40x magnification. Pre clean.

#### **CONCLUSION**

The grooving of multilayer silicon wafer was investigated on SYNOVA LDS200. This machine is based on the MicroJet<sup>®</sup> technology and combines the advantages of the high energy pulsed laser with a hair-thin water jet. While the laser is used for material ablation, the water jet is used for guiding the laser light, cooling the edges and preventing the sample from particle contamination, advantages that are essential for cutting of such kind of materials with high quality.

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